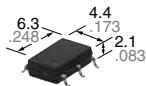


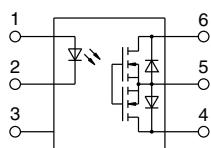


**Miniature SOP6-pin type
Low on-resistance
200V/400V load voltage**

**PhotoMOS®
RF SOP 1 Form A
Low on-resistance (AQV220NS)**



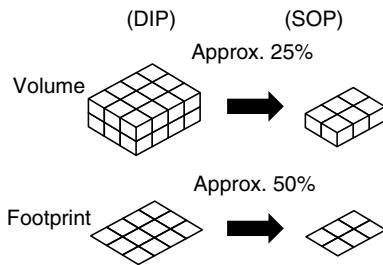
mm inch



RoHS compliant

FEATURES

1. Miniature SOP4-pin package
(W) 4.4 × (L) 6.3 × (H) 2.1 mm (W) .173×(L) .248× (H) .083 inch —approx. 25% of the volume and 50% of the footprint size of DIP type PhotoMOS.



2. Low output capacitance and high response speed

The capacitance between output terminals is small; Typ. 10pF. This enables a fast operation speed of Typ. 0.1ms (AQY224NS).

3. Low-level off state leakage current
4. Controls low-level analog signals

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computers
- Industrial robots
- High-speed inspection machines

TYPES

	Output rating*		Package	Part No.			Packing quantity		
	Load voltage	Load current		Tape and reel packing style		Tube	Tape and reel		
				Tube packing style	Picked from the 1/2/3-pin side				
AC/DC dual use	200 V	50 mA	SOP6-pin	AQV227NS	AQV227NSX	AQV227NSZ	1 tube contains: 75 pcs. 1 batch contains: 1,000 pcs.	1,000 pcs.	
	400 V	40 mA		AQV224NS	AQV224NSX	AQV224NSZ			

*Indicate the peak AC and DC values.

Note: For space reasons, the two initial letters of the part number "AQ" and the packing style indicator "X" or "Z" are not marked on the device.
(Ex. the label for product number AQV227NS is V227NS)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV227NS	AQV224NS	Remarks
Input	LED forward current	I _F		50 mA		
	LED reverse voltage	V _R		5 V		
	Peak forward current	I _{FP}		1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75 mW		
Output	Load voltage (peak AC)	V _L	A	200 V	400 V	
	Continuous load current	I _L		0.05 A	0.04 A	A connection: Peak AC, DC B, C connection: DC
	Peak load current	I _{peak}		0.06 A	0.05 A	
	Power dissipation	P _{out}	C	0.08 A	0.06 A	
	Total power dissipation	P _T		0.15 A	0.12 A	A connection: 100 ms (1 shot), V _L = DC
I/O isolation voltage		V _{iso}		450 mW		
Ambient temperature		T _{opr}		500 mW		
Operating		T _{stg}		1,500 Vrms		
Storage				-40 to +85°C -40 to +185°F		(Non-icing at low temperatures)
				-40 to +100°C -40 to +212°F		

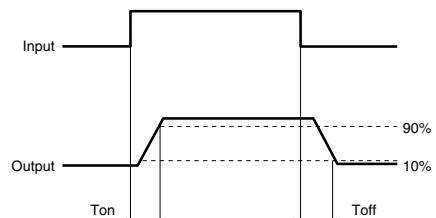
RF SOP 1 Form A Low on-resistance (AQV220NS)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV227NS	AQV224NS	Condition
Input	LED operate current	Typical	I_{Fon}	—	0.7 mA		$I_L = \text{Max.}$
		Maximum			3 mA		
	LED turn off current	Minimum	I_{Foff}	—	0.4 mA		$I_L = \text{Max.}$
		Typical			0.65 mA		
Output	LED dropout voltage	Typical	V_F	—	1.25 V (1.14 V at $I_F = 5 \text{ mA}$)		$I_F = 50 \text{ mA}$
		Maximum			1.5 V		
	On resistance	Typical	R_{on}	A	30 Ω	70 Ω	$I_F = 5 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
		Maximum			50 Ω	100 Ω	
		Typical	R_{on}	B	16 Ω	55 Ω	$I_F = 5 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
		Maximum			25 Ω	70 Ω	
Transfer characteristics	Typical	R_{on}	C	—	8 Ω	28 Ω	$I_F = 5 \text{ mA}$ $I_L = \text{Max.}$ Within 1 s
		Maximum			12.5 Ω	35 Ω	
	Output capacitance	Typical	C_{out}	—	10 pF		$I_F = 0$ $V_B = 0$ $f = 1 \text{ MHz}$
		Maximum			15 pF		
	Off state leakage current	Maximum	I_{leak}	—	*10 nA		$I_F = 0$ $V_L = \text{Max.}$

*Available as custom orders (1 nA or less)

**Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Min.	Max.	Unit
AQV227NS	LED current	I_F	5	30	mA
	Load voltage (Peak AC)	V_L	—	160	V
AQV224NS	Continuous load current (A connection)	I_L	—	0.05	A
	Load voltage (Peak AC)	V_L	—	320	V
	Continuous load current (A connection)	I_L	—	0.04	A

■ These products are not designed for automotive use.

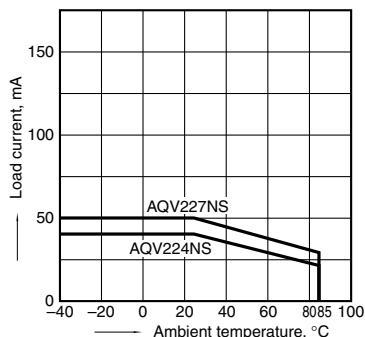
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

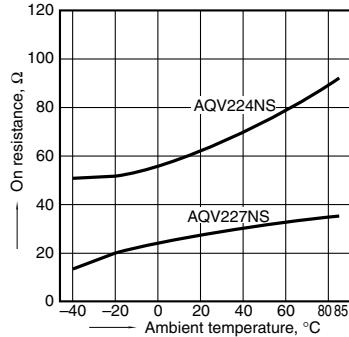
Allowable ambient temperature: -40 to $+85^\circ\text{C}$
 -40 to $+185^\circ\text{F}$

Type of connection: A



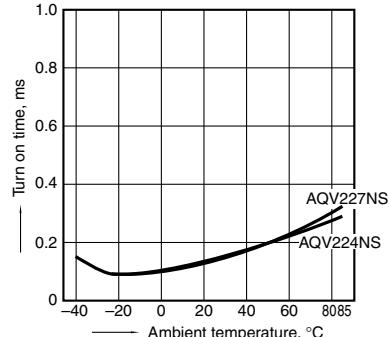
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



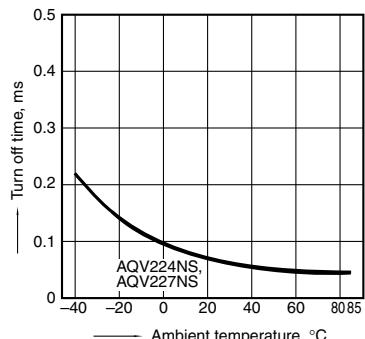
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



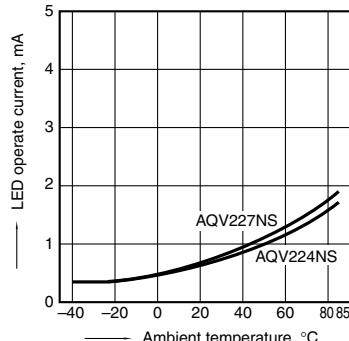
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



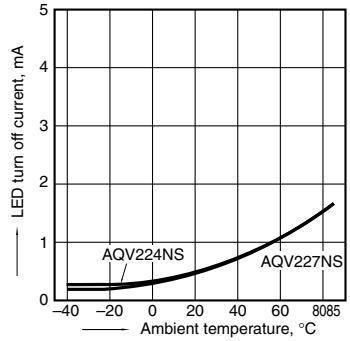
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



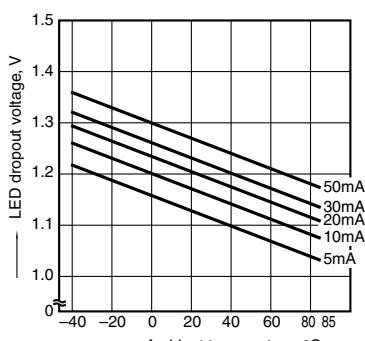
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



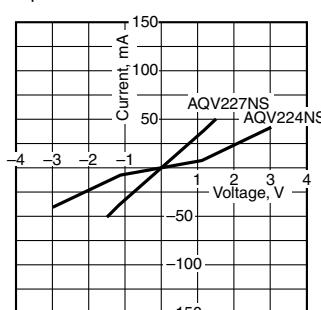
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
LED current: 5 to 50 mA



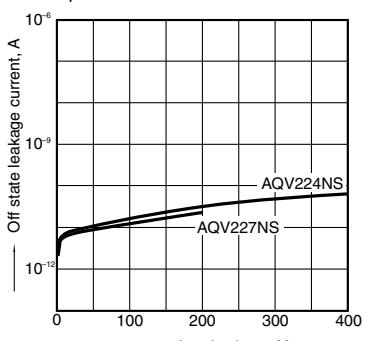
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

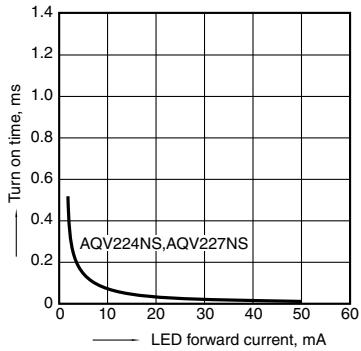
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



RF SOP 1 Form A Low on-resistance (AQV220NS)

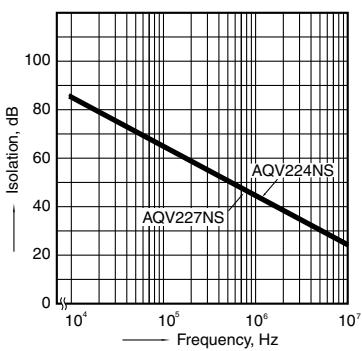
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



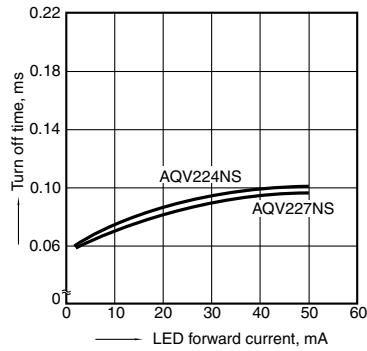
13. Isolation vs. frequency characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



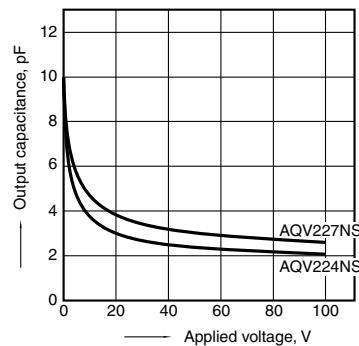
11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



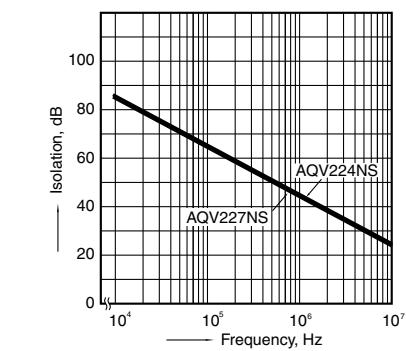
12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz, 30mVrms;
Ambient temperature: 25°C 77°F



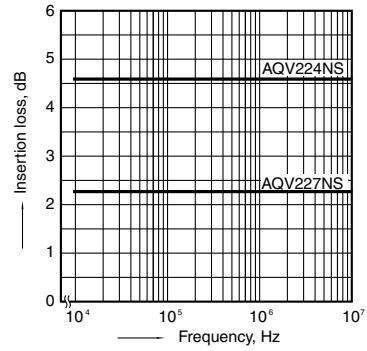
13. Isolation vs. frequency characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



14. Insertion loss vs. frequency characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



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